Docket No: 740756-2719

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Patent Application of	)	
Shunpei YAMAZAKI et al.	)	
Based On Application No. 10/084,428	) Attn:	Applications
Filed: February 28, 2002	)	Branch
For: SEMICONDUCTOR DEVICE HAVING	)	
SEMICONDUCTOR CIRCUIT FORMED BY	)	
SEMICONDUCTOR ELEMENTS AND METHOR	<b>)</b>	
FOR MANUFACTURING THE SAME	) Date:	: March 31, 2004

## **INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98. Pursuant to 37 C.F.R. § 1.98, a copy of each of the documents cited is enclosed.

The references listed on the attached Form PTO-1449 were cited in parent application Serial No. 10/084,428 filed February 28, 2002, from which priority is claimed under 35 U.S.C. 120.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned.

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The Commissioner is hereby authorized to charge any fees connected with this filing which may be required now, or credit any overpayment to Deposit Account No. 19-2380.

Respectfully submitted,

By:

Registration No. 35,483

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE				Complete if Known		
			OSLIDE	Application Number	New Application	
STATEMENT BY APPLICANT		Filing Date	March 31, 2004			
		First Named Inventor	Shunpei YAMAZAKI et al.			
(use as many sheets as necessary)	Art Unit	2826				
		Examiner Name	S. Wilson			
Sheet	1	of	1	Attorney Docket Number	740756-2719	

U.S. PATENT DOCUMENTS					
Examiner Initials	Cite No.1	U.S. Patent Document  Number - Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-5,861,656	01/19/1999	Keri	
		US-5,471,330	11/28/1995	Sarma	-
		US-6,147,667	11/14/2000	Yamazaki et al	
-	1	US-5,767,531	06/16/1998	Yoshinouchi	
		US-6,246,070	06/12/2001	Yamazaki et al	
		US-5,763,301	06/09/1998	Rha et al	
		US-5,818,067	10/06/1998	Rha et al	
		US-6,147,667	11/14/2000	Yamazaki et al.	
		US-5,403,762	04/04/1995	Takemura	
		US-5,342,545	08/30/1994	Yamada et al.	
		US-5,471,330	11/28/1995	Sarma	

		F	OREIGN PATENT I	OCUMENTS		·
Examiner Initials	Cite No.1	Foreign Patent Document  Kind Code <sup>3</sup> Country Code <sup>3</sup> Number <sup>4</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Application of Cited Document	Pages, Cohumns, Lines, Where Relevant Passages or Relevant Figures Appear	T⁴
		JP 07-142734-A	06/02/1995			Abstract
		JP 58-163722-A	09/28/1983	Yabuki et al		Abstract
		JP 61-070780-A	04/11/1986	Oda et al		Abstract
		OTHER PRIOR	ART – NON PATENT	LITERATURE DOCUMENTS		
Examiner Initials	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.			T <sup>2</sup>	
	Lim et al. "High Performance Amorphous Silicon Thin Film Transistor with a Planarize SIN <sub>x</sub> /BCB Double-Layered Gate Insulator", AM-LCD '98 pp. 73-76		tor with a Planarized			
Won et al. "28.3: A High-Resolution Full Color TFT-LCD on Transparent Plastic", SID 03 DIGEST, pp. 992-995  Jang et al. "32.1: Invited Paper: Amorphous Silicon Thin-Film Transistors with Planarized Gate Insulators" (4 pages)						
		Wolf, Silicon Processing for 354, 356-357, 359.	or the VLSI Era, 1	990, Lattice Press, Volu	me 2, p. 273-274,	

Examiner	Date	
Signature	 Considered	

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>&</sup>lt;sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at <a href="www.uspto.gov">www.uspto.gov</a> or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached